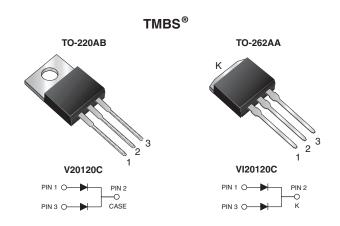


# **Dual High Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.54 \text{ V}$  at  $I_F = 5 \text{ A}$ 



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 10 A				
$V_{RRM}$	120 V				
I <sub>FSM</sub>	120 A				
V <sub>F</sub> at I <sub>F</sub> = 10 A	0.64 V				
T <sub>J</sub> max.	150 °C				
Package	TO-220AB, TO-262AA				
Diode variation	Common cathode				

### **FEATURES**

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses

op, low power losses

compliant

HALOGEN

FREE

- High efficiency operation
  Solder dip 275 °C max. 10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912">www.vishav.com/doc?99912</a>

#### TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

## **MECHANICAL DATA**

Case: TO-220AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS compliant, and commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs max.

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	V20120C	VI20120C	UNIT	
Max. repetitive peak reverse voltage		V <sub>RRM</sub>	120		V	
Max. average forward rectified current (fig. 1)	per device	I <sub>F(AV)</sub>	20		А	
	per diode		10			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	120		А	
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 (	000	V/µs	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-40 to	+150	°C	



<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.62	-	V	
	I <sub>F</sub> = 10 A			0.81	0.90		
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.54	-		
	I <sub>F</sub> = 10 A			0.64	0.72		
Reverse current per diode	V <sub>R</sub> = 90 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> (2)	8	=	μΑ	
		T <sub>A</sub> = 125 °C		6	=	mA	
	I V <sub>□</sub> = 120 V —	T <sub>A</sub> = 25 °C		-	700	μΑ	
		T <sub>A</sub> = 125 °C		14	45	mA	

### Notes

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	V20120C VI20120C		UNIT	
Typical thermal resistance per diode	$R_{ heta JC}$	2.8		°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	V20120C-M3/4W	1.88	4W	50/tube	Tube		
TO-262AA	VI20120C-M3/4W	1.45	4W	50/tube	Tube		

## **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub> = 25 °C unless otherwise noted)

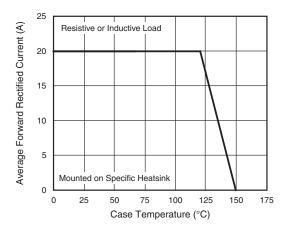
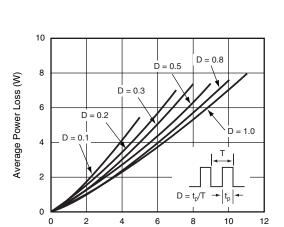


Fig. 1 - Maximum Forward Current Derating Curve



Average Forward Current (A)

Fig. 2 - Forward Power Loss Characteristics Per Diode

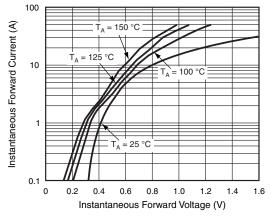


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

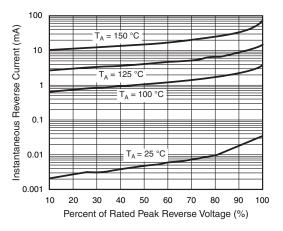


Fig. 4 - Typical Reverse Characteristics Per Diode

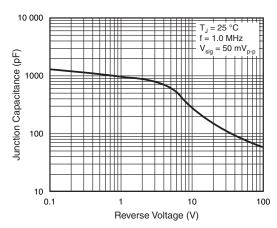


Fig. 5 - Typical Junction Capacitance Per Diode

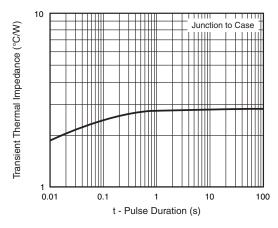
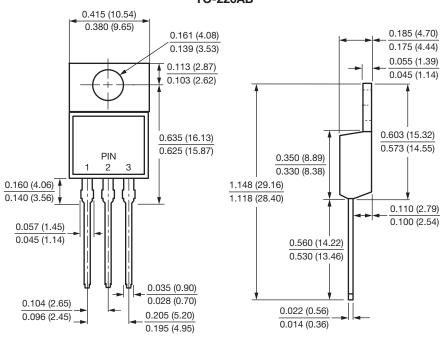


Fig. 6 - Typical Transient Thermal Impedance Per Diode

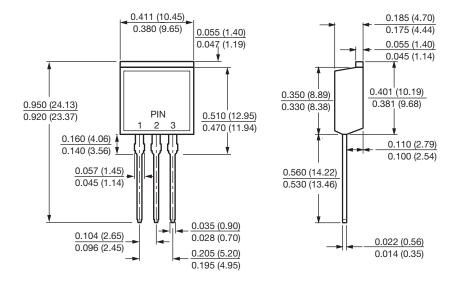


## **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

#### TO-220AB



#### **TO-262AA**





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